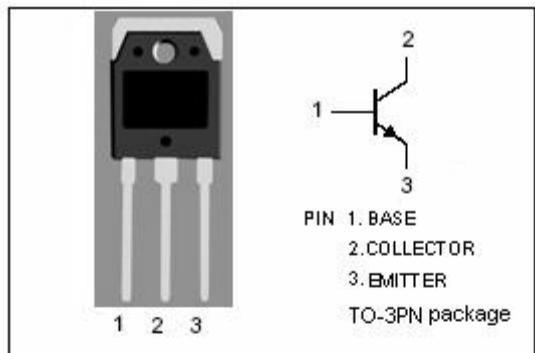


**DESCRIPTION**

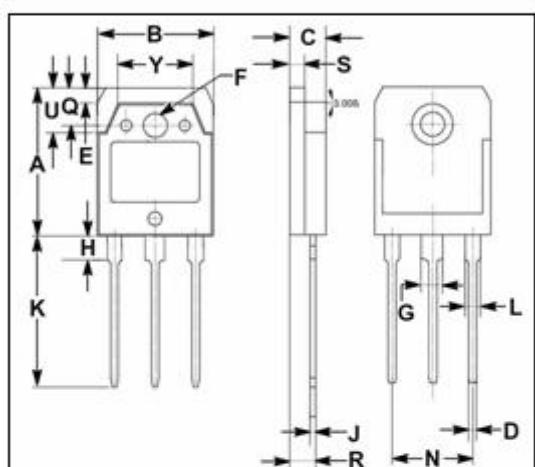
- High Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO}=250V$ (Min)
- Good Linearity of  $h_{FE}$
- Complement to Type NJW0302G

**APPLICATIONS**

- Designed for high fidelity audio amplifier and other linear applications

**ABSOLUTE MAXIMUM RATINGS(Ta=25°C)**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	250	V
$V_{CEO}$	Collector-Emitter Voltage	250	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current-Continuous	15	A
$I_B$	Base Current-Continuous	1.5	A
$P_C$	Collector Power Dissipation @ $T_c=25^\circ C$	150	W
$T_J$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature Range	-65~150	°C



DIM	mm	
	MIN	MAX
A	19.60	20.10
B	15.50	15.70
C	4.70	4.90
D	0.90	1.10
E	1.90	2.10
F	3.40	3.60
G	2.90	3.20
H	3.20	3.40
J	0.595	0.605
K	20.00	20.70
L	1.90	2.20
N	10.89	10.91
Q	4.90	5.10
R	3.35	3.45
S	1.995	2.100
U	5.90	6.10
Y	9.90	10.10

# SPTECH Product Specification

## SPTECH Silicon NPN Power Transistor

NJW0281G

### ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 30mA ; I <sub>B</sub> = 0	250			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5.0A; I <sub>B</sub> = 0.5A			1.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 5.0 A, V <sub>CE</sub> = 5.0 V			1.2	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 250V ; I <sub>E</sub> = 0			10	µ A
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			5	µ A
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 0.5A ; V <sub>CE</sub> = 5V	75		150	
h <sub>FE1</sub>	DC Current Gain	I <sub>C</sub> = 1A ; V <sub>CE</sub> = 5V	75		150	
h <sub>FE2</sub>	DC Current Gain	I <sub>C</sub> = 3A ; V <sub>CE</sub> = 5V	75		150	
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 10V; f <sub>test</sub> = 1.0MHz			700	pF
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> =1A ; V <sub>CE</sub> = 5V ; f <sub>test</sub> = 1.0MHz	20			MHz

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